

# TLP200D

PBX

MODEM · FAX CARD

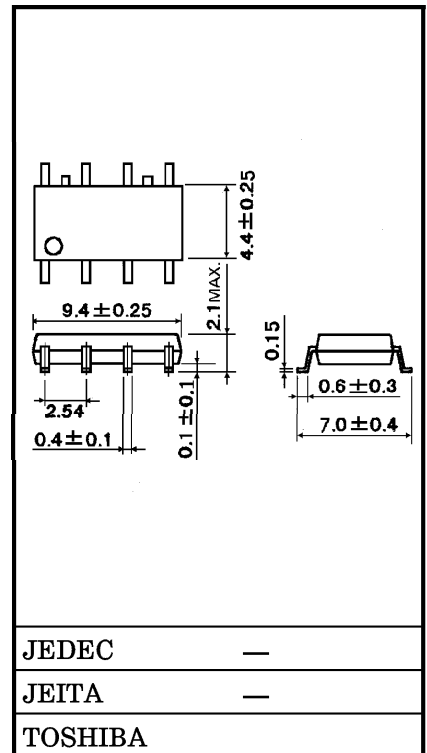
MEASUREMENT INSTRUMENT

The TOSHIBA TLP200D consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 8 pin SOP.

The TLP200D is a 2-Form-A switch which is suitable for replacement of mechanical relays in many applications which require space savings.

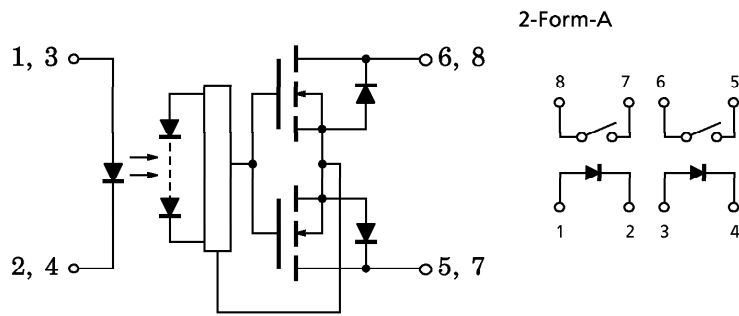
- SOP 8 pin (2.54SOP8) : 2-Form-A
- Peak Off-State Voltage : 200 V (MIN.)
- Trigger LED Current : 3 mA (MAX.)
- On-State Current : 200 mA (MAX.)
- On-State Resistance : 8 Ω (MAX.)
- Isolation Voltage : 1500 V<sub>rms</sub> (MIN.)
- UL Recognized : UL1577, File No. E67349

Unit in mm

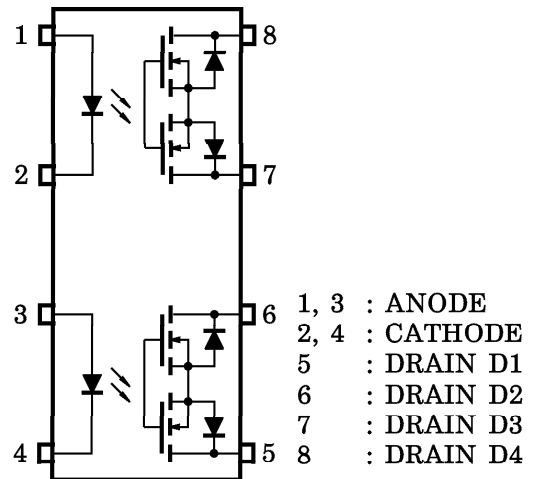


Weight : 0.2 g

**SCHEMATIC**



**PIN CONFIGURATION (TOP VIEW)**



## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I <sub>F</sub>	50	mA
	Forward Current Derating (Ta ≥ 25°C)	ΔI <sub>F</sub> /°C	-0.5	mA/°C
	Pulse Forward Current (100 μs pulse, 100 pps)	I <sub>FP</sub>	1	A
	Reverse Voltage	V <sub>R</sub>	5	V
	Junction Temperature	T <sub>j</sub>	125	°C
DETECTOR	Off-State Output Terminal Voltage	V <sub>OFF</sub>	200	V
	On-State Current	I <sub>ON</sub>	200	mA
	On-State RMS Current Derating (Ta ≥ 25°C)	ΔI <sub>ON</sub> /°C	-2.0	mA/°C
	Junction Temperature	T <sub>j</sub>	125	°C
Storage Temperature Range		T <sub>stg</sub>	-55~125	°C
Operating Temperature Range		T <sub>opr</sub>	-40~85	°C
Lead Soldering Temperature (10 s)		T <sub>sol</sub>	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 2)		BV <sub>S</sub>	1500	V <sub>rms</sub>

(Note 1) : Two channels operating simultaneously.

(Note 2) : Device considered a two-terminal device : pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V <sub>DD</sub>	—	150	200	V
Forward Current	I <sub>F</sub>	5	7.5	25	mA
On-State Current	I <sub>ON</sub>	—	—	130	mA
Operating Temperature	T <sub>opr</sub>	-20	—	65	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	$I_{OFF}$	$V_{OFF} = 200 \text{ V}$	—	—	1	$\mu\text{A}$
	Capacitance	$C_{OFF}$	$V = 0, f = 1 \text{ MHz}$	—	100	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	$I_{FT}$	$I_{ON} = 200 \text{ mA}$	—	1	3	mA
On-State Resistance	$R_{ON}$	$I_{ON} = 200 \text{ mA}, I_F = 5 \text{ mA}$	—	5	8	$\Omega$

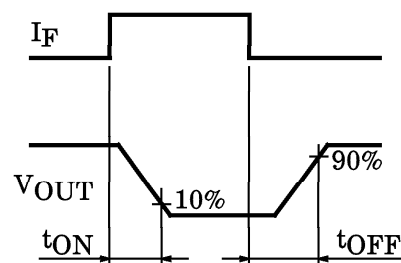
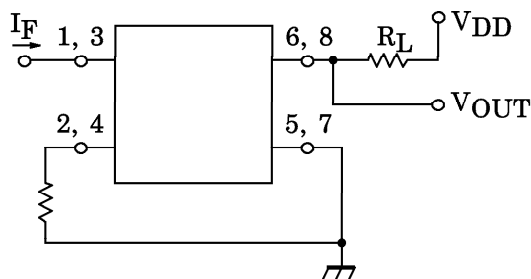
ISOLATION CHARACTERISTICS (Ta = 25°C)

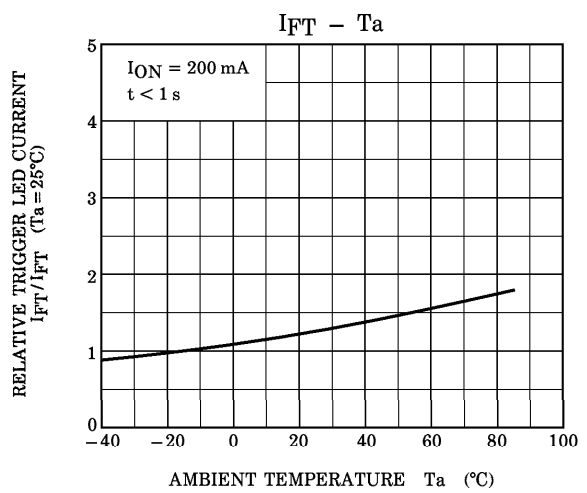
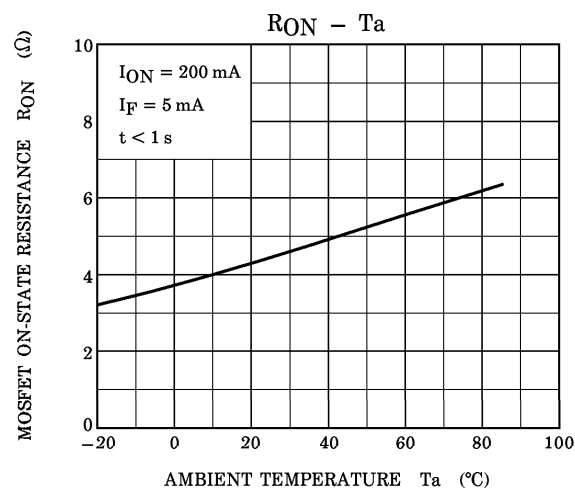
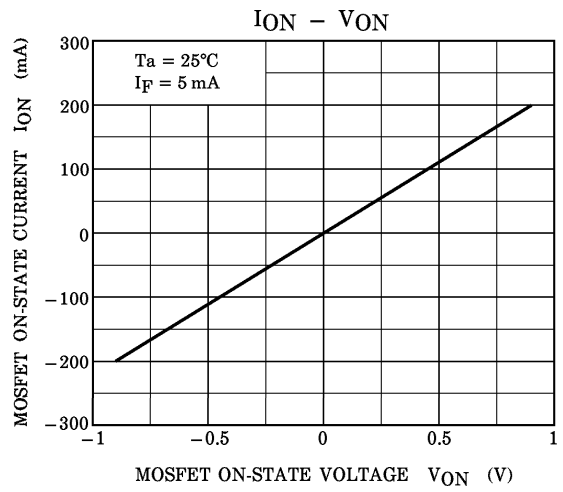
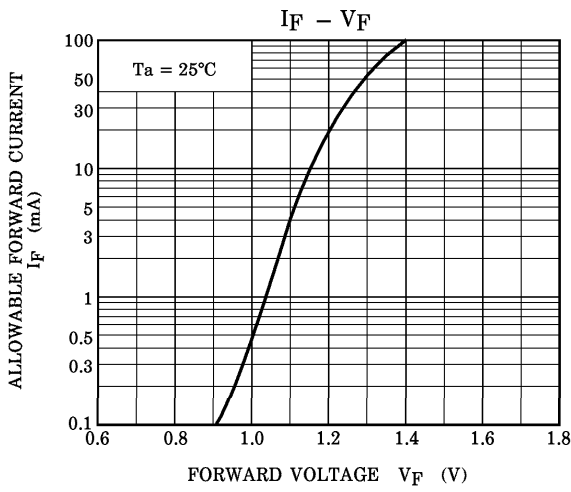
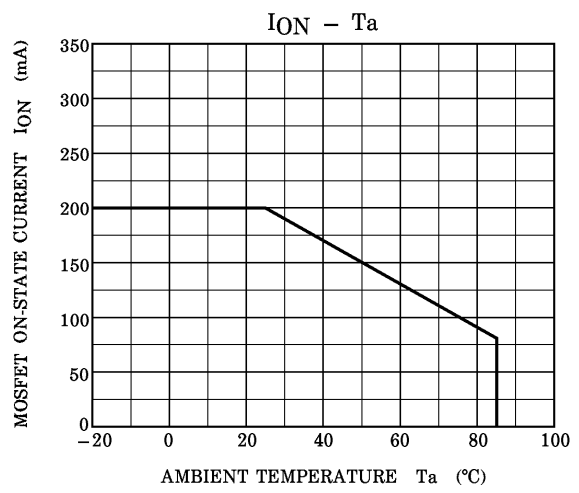
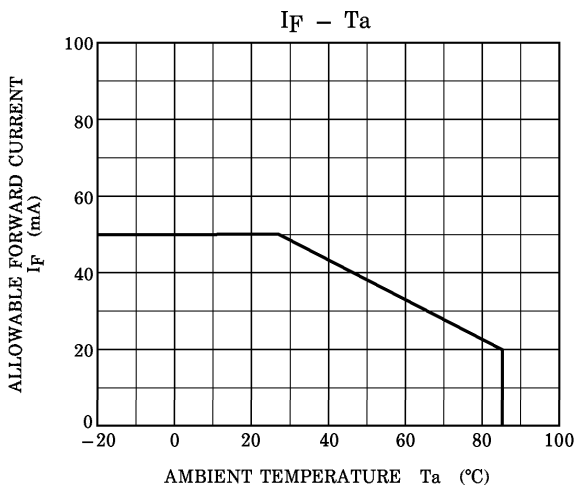
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	$C_S$	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	$R_S$	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage	$BV_S$	AC, 1 minute	1500	—	—	$V_{rms}$
		AC, 1 second, in oil	—	3000	—	
		DC, 1 minute, in oil	—	3000	—	Vdc

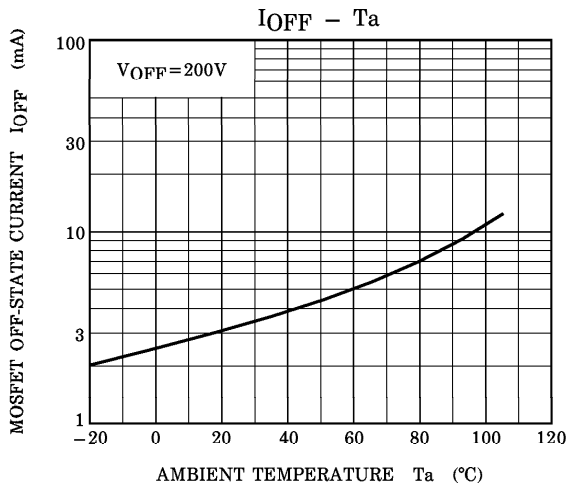
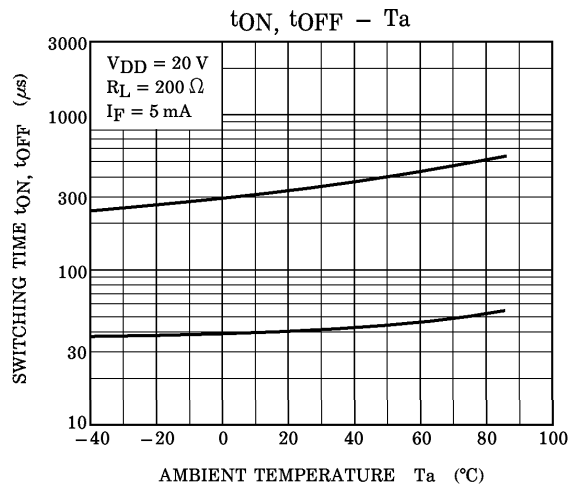
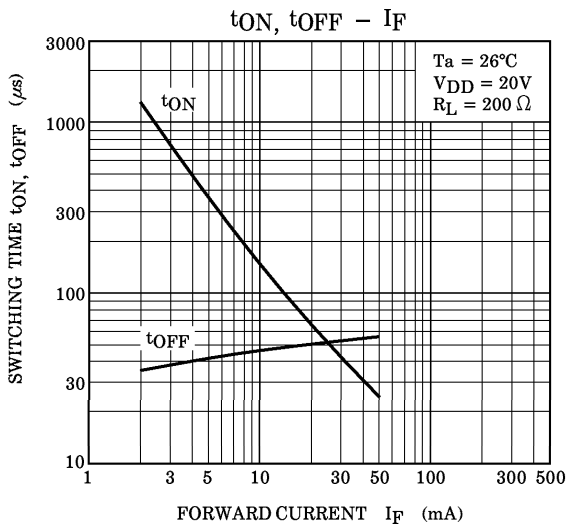
SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	$t_{ON}$	$R_L = 200 \Omega$ (Note 3)	—	0.6	1.5	ms
Turn-off Time	$t_{OFF}$	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	0.1	1.0	

(Note 3) : Switching Time Test Circuit







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